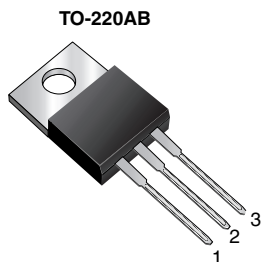




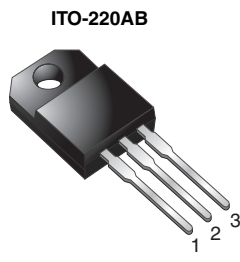
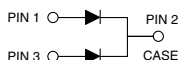
## Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.50\text{ V}$  at  $I_F = 5\text{ A}$

TMBS®



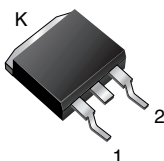
V30120C



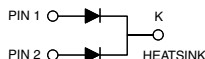
VF30120C



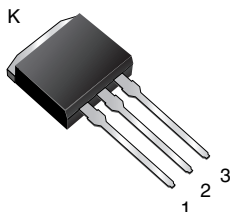
TO-263AB



VB30120C



TO-262AA



VI30120C



### PRIMARY CHARACTERISTICS

|                              |                                         |
|------------------------------|-----------------------------------------|
| $I_{F(AV)}$                  | 2 x 15 A                                |
| $V_{RRM}$                    | 120 V                                   |
| $I_{FSM}$                    | 150 A                                   |
| $V_F$ at $I_F = 15\text{ A}$ | 0.68 V                                  |
| $T_J$ max.                   | 150 °C                                  |
| Package                      | TO-220AB, ITO-220AB, TO-263AB, TO-262AA |
| Diode variations             | Common cathode                          |

### MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

| PARAMETER                                                                                                               | SYMBOL         | V30120C     | VF30120C | VB30120C | VI30120C | UNIT             |
|-------------------------------------------------------------------------------------------------------------------------|----------------|-------------|----------|----------|----------|------------------|
| Max. repetitive peak reverse voltage                                                                                    | $V_{RRM}$      | 120         |          |          |          | V                |
| Max. average forward rectified current<br>(fig. 1)                                                                      | $I_{F(AV)}$    | 30          |          |          |          | A                |
|                                                                                                                         |                | 15          |          |          |          | A                |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode                            | $I_{FSM}$      | 150         |          |          |          | A                |
| Non-repetitive avalanche energy at $T_J = 25\text{ °C}$ , $L = 60\text{ mH}$ per diode                                  | $E_{AS}$       | 130         |          |          |          | mJ               |
| Peak repetitive reverse current at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz, $T_J = 38\text{ °C} \pm 2\text{ °C}$ per diode | $I_{RRM}$      | 0.5         |          |          |          | A                |
| Voltage rate of change (rated $V_R$ )                                                                                   | $dV/dt$        | 10 000      |          |          |          | V/ $\mu\text{s}$ |
| Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1\text{ min}$                                         | $V_{AC}$       | 1500        |          |          |          | V                |
| Operating junction and storage temperature range                                                                        | $T_J, T_{STG}$ | -40 to +150 |          |          |          | °C               |

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



RoHS  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs max.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                                              | TEST CONDITIONS         |                         | SYMBOL          | TYP.       | MAX. | UNIT |
|--------------------------------------------------------|-------------------------|-------------------------|-----------------|------------|------|------|
| Breakdown voltage                                      | I <sub>R</sub> = 1.0 mA | T <sub>A</sub> = 25 °C  | V <sub>BR</sub> | 120 (min.) | -    | V    |
| Instantaneous forward voltage per diode <sup>(1)</sup> | I <sub>F</sub> = 5 A    | T <sub>A</sub> = 25 °C  | V <sub>F</sub>  | 0.56       | -    | V    |
|                                                        | I <sub>F</sub> = 7.5 A  |                         |                 | 0.71       | -    |      |
|                                                        | I <sub>F</sub> = 15 A   |                         |                 | 0.86       | 0.97 |      |
|                                                        | I <sub>F</sub> = 5 A    | T <sub>A</sub> = 125 °C |                 | 0.50       | -    |      |
|                                                        | I <sub>F</sub> = 7.5 A  |                         |                 | 0.60       | -    |      |
|                                                        | I <sub>F</sub> = 15 A   |                         |                 | 0.68       | 0.76 |      |
| Reverse current per diode <sup>(2)</sup>               | V <sub>R</sub> = 90 V   | T <sub>A</sub> = 25 °C  | I <sub>R</sub>  | 11         | -    | μA   |
|                                                        |                         | T <sub>A</sub> = 125 °C |                 | 8          | -    | mA   |
|                                                        | V <sub>R</sub> = 120 V  | T <sub>A</sub> = 25 °C  |                 | -          | 800  | μA   |
|                                                        |                         | T <sub>A</sub> = 125 °C |                 | 17         | 50   | mA   |

**Notes**<sup>(1)</sup> Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle<sup>(2)</sup> Pulse test: Pulse width  $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                            | SYMBOL          | V30120C | VF30120C | VB30120C | VI30120C | UNIT                 |
|--------------------------------------|-----------------|---------|----------|----------|----------|----------------------|
| Typical thermal resistance per diode | $R_{\theta JC}$ | 2.2     | 4.5      | 2.2      | 2.2      | $^{\circ}\text{C/W}$ |

**ORDERING INFORMATION** (Example)

| PACKAGE   | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|-----------|----------------|-----------------|--------------|---------------|---------------|
| TO-220AB  | V30120C-E3/4W  | 1.89            | 4W           | 50/tube       | Tube          |
| ITO-220AB | VF30120C-E3/4W | 1.75            | 4W           | 50/tube       | Tube          |
| TO-263AB  | VB30120C-E3/4W | 1.38            | 4W           | 50/tube       | Tube          |
| TO-263AB  | VB30120C-E3/8W | 1.38            | 8W           | 800/reel      | Tape and reel |
| TO-262AA  | VI30120C-E3/4W | 1.46            | 4W           | 50/tube       | Tube          |

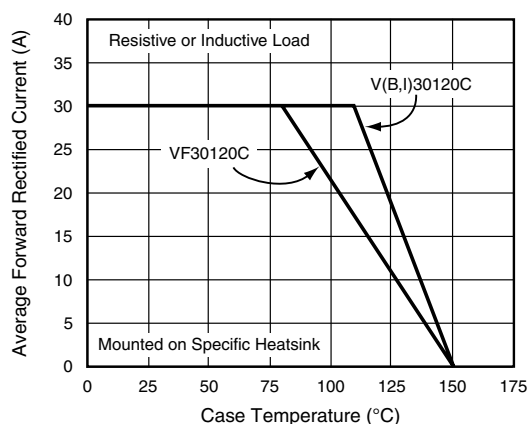
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

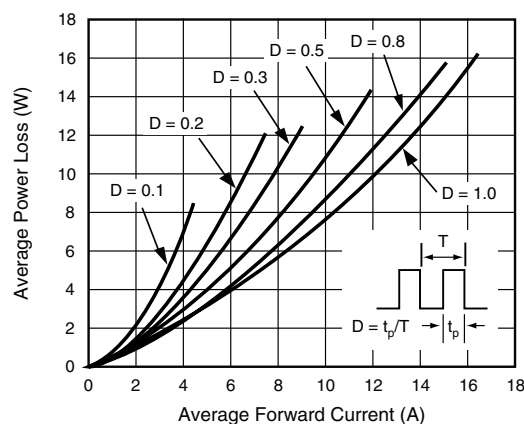


Fig. 2 - Forward Power Loss Characteristics Per Diode

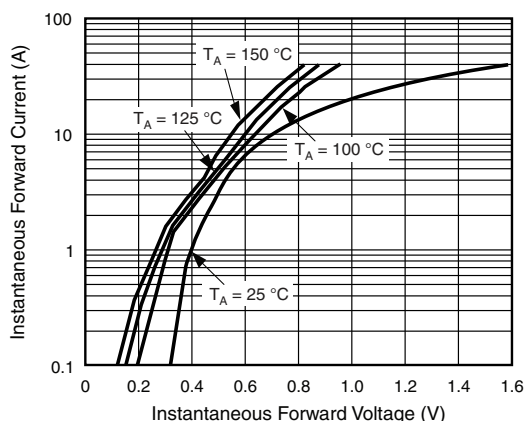


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

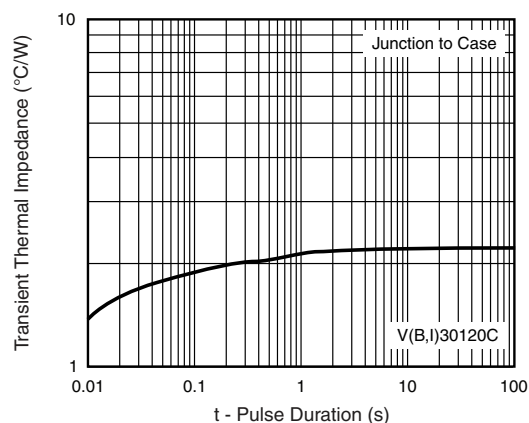


Fig. 6 - Typical Transient Thermal Impedance Per Diode

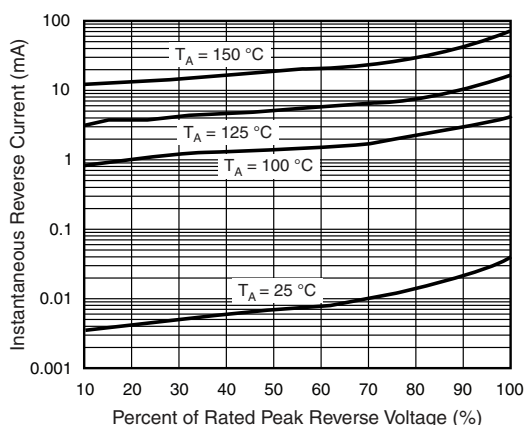


Fig. 4 - Typical Reverse Characteristics Per Diode

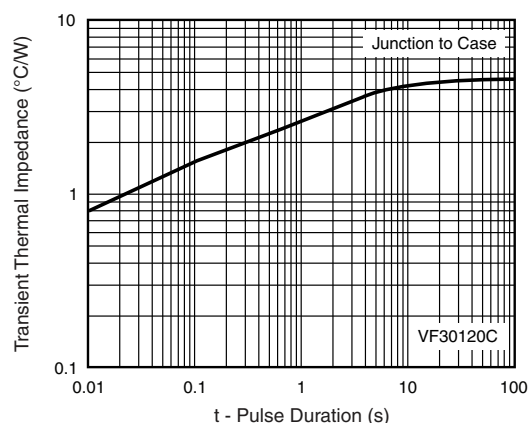


Fig. 7 - Typical Transient Thermal Impedance Per Diode

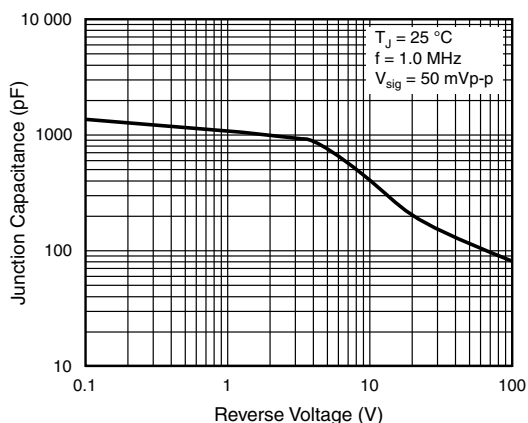
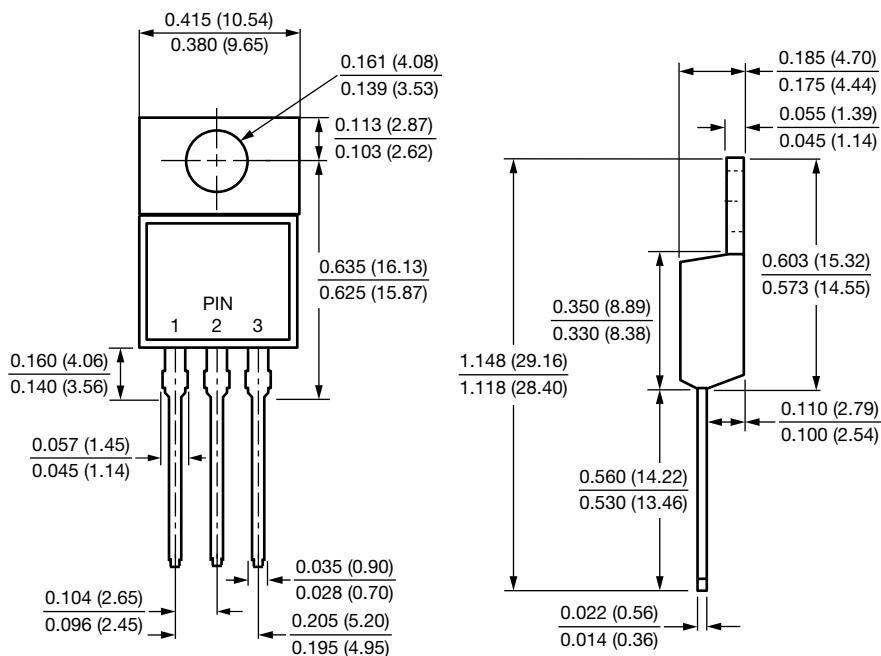


Fig. 5 - Typical Junction Capacitance Per Diode

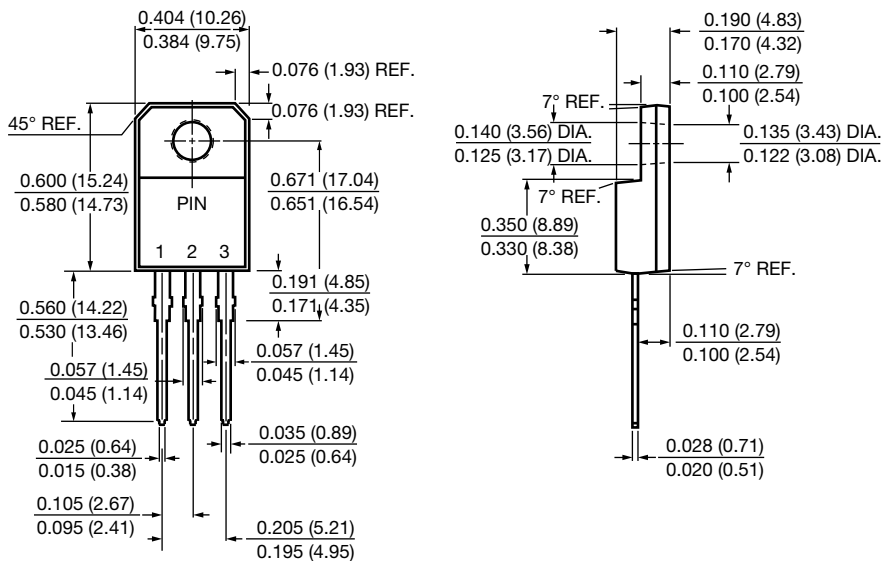


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-220AB

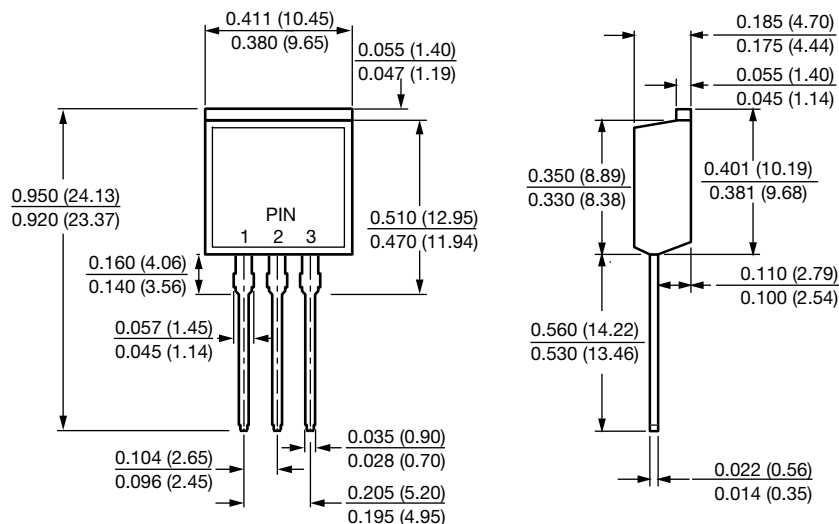


### ITO-220AB

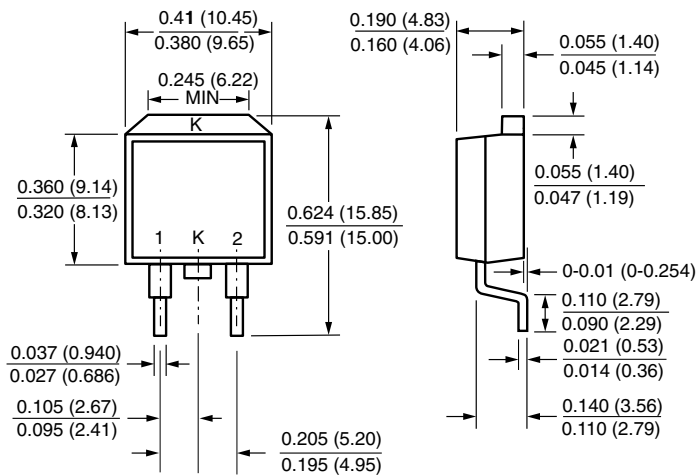




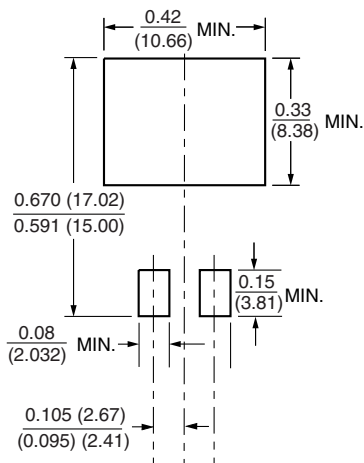
## TO-262AA



## TO-263AB



## Mounting Pad Layout





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